



STTH61R04TV

Ultrafast recovery diode

Main product characteristics

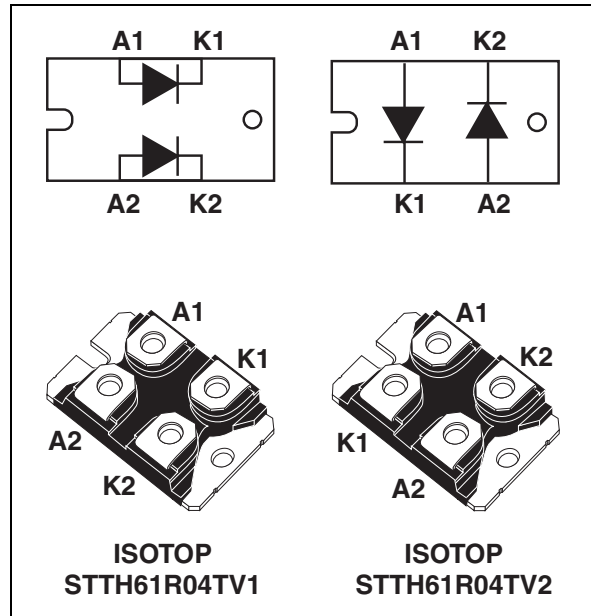
| | |
|----------------|----------|
| $I_{F(AV)}$ | 2 x 30 A |
| V_{RRM} | 400 V |
| T_j | 150° C |
| V_F (typ) | 0.95 V |
| t_{rr} (typ) | 24 ns |

Features and benefits

- Ultrafast
- Very low switching losses
- High frequency and high pulsed current operation
- Low leakage current
- Insulated package:
 - ISOTOP
Electrical insulation = 2500 V_{RMS}
Capacitance = 45 pF

Description

The STTH61R04TV series uses ST's new 400 V planar Pt doping technology. The STTH61R04 is specially suited for switching mode base drive and transistor circuits, such as welding equipment.



Order codes

| Part Number | Marking |
|--------------|--------------|
| STTH61R04TV1 | STTH61R04TV1 |
| STTH61R04TV2 | STTH61R04TV2 |

1 Characteristics

Table 1. Absolute ratings (limiting values per diode at 25° C, unless otherwise specified)

| Symbol | Parameter | | | | Value | Unit |
|---------------------|--|---|--|------------------------|--------------|------|
| V _{RRM} | Repetitive peak reverse voltage | | | | 400 | V |
| V _{RSM} | Non repetitive peak reverse voltage | | | | 400 | V |
| I _{F(RMS)} | RMS forward current | | | | 60 | A |
| I _{F(AV)} | Average forward current, δ = 0.5 | Per diode | | T _c = 80° C | 30 | A |
| I _{FRM} | Repetitive peak forward current | t _p = 5 μs, F = 1 kHz square | | | 900 | A |
| I _{FSM} | Surge non repetitive forward current | t _p = 10 ms Sinusoidal | | | 350 | A |
| T _{stg} | Storage temperature range | | | | -65 to + 150 | °C |
| T _j | Maximum operating junction temperature | | | | 150 | °C |

Table 2. Thermal parameters

| Symbol | Parameter | | Value | Unit |
|---------------|-----------------------------|-----------|-------|------|
| $R_{th(j-c)}$ | Junction to case | Per diode | 1.5 | °C/W |
| | | Total | 0.8 | |
| $R_{th(c)}$ | Coupling thermal resistance | | 0.1 | |

When the diodes are used simultaneously:

$$\Delta T_{j(\text{diode1})} = P_{(\text{diode1})} \times R_{th(j-c)} \text{ (per diode)} + P_{(\text{diode2})} \times R_{th(c)}$$

Table 3. Static electrical characteristics

| Symbol | Parameter | Test conditions | | Min. | Typ | Max. | Unit |
|-------------|-------------------------|----------------------------|----------------------|------|------|------|---------------|
| $I_R^{(1)}$ | Reverse leakage current | $T_j = 25^\circ \text{C}$ | $V_R = V_{RRM}$ | | | 15 | μA |
| | | $T_j = 125^\circ \text{C}$ | | | 15 | 150 | |
| $V_F^{(2)}$ | Forward voltage drop | $T_j = 25^\circ \text{C}$ | $I_F = 30 \text{ A}$ | | | 1.45 | V |
| | | $T_j = 100^\circ \text{C}$ | | | 1.05 | 1.3 | |
| | | $T_j = 150^\circ \text{C}$ | | | 0.95 | 1.20 | |

1. Pulse test: $t_p = 5 \text{ ms}$, $\delta < 2 \%$

2. Pulse test: $t_p = 380 \mu\text{s}$, $\delta < 2 \%$

To evaluate the conduction losses use the following equation:

$$P = 0.9 \times I_{F(AV)} + 0.01 \times I_{F(RMS)}^2$$

Table 4. Dynamic characteristics

| Symbol | Parameter | Test conditions | Min. | Typ | Max. | Unit |
|----------|--------------------------|---|------|-----|------|------|
| t_{rr} | Reverse recovery time | $I_F = 1\text{ A}$, $di_F/dt = -50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $T_j = 25^\circ\text{C}$ | | | 65 | ns |
| | | $I_F = 1\text{ A}$, $di_F/dt = -100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $T_j = 25^\circ\text{C}$ | | 31 | 45 | |
| | | $I_F = 1\text{ A}$, $di_F/dt = -200\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $T_j = 25^\circ\text{C}$ | | 24 | 35 | |
| I_{RM} | Reverse recovery current | $I_F = 30\text{ A}$, $di_F/dt = -200\text{ A}/\mu\text{s}$, $V_R = 320\text{ V}$, $T_j = 125^\circ\text{C}$ | | 10 | 14 | A |
| S | Softness factor | $I_F = 30\text{ A}$, $di_F/dt = -200\text{ A}/\mu\text{s}$, $V_R = 320\text{ V}$, $T_j = 125^\circ\text{C}$ | | 0.4 | | |
| t_{fr} | Forward recovery time | $I_F = 30\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_{FR} = 1.5 \times V_{Fmax}$, $T_j = 25^\circ\text{C}$ | | 250 | | ns |
| V_{FP} | Forward recovery voltage | $I_F = 30\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $T_j = 25^\circ\text{C}$ | | 2.9 | | V |

Figure 1. Conduction losses versus average current

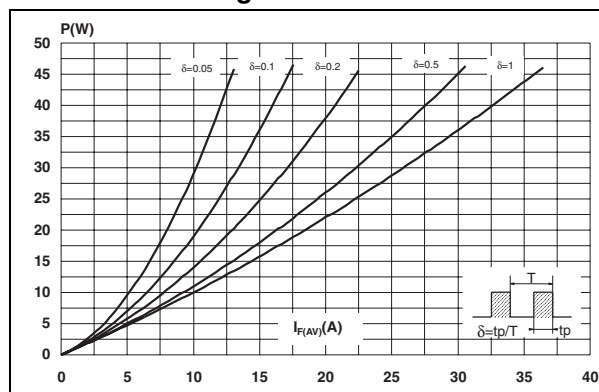


Figure 2. Forward voltage drop versus forward current

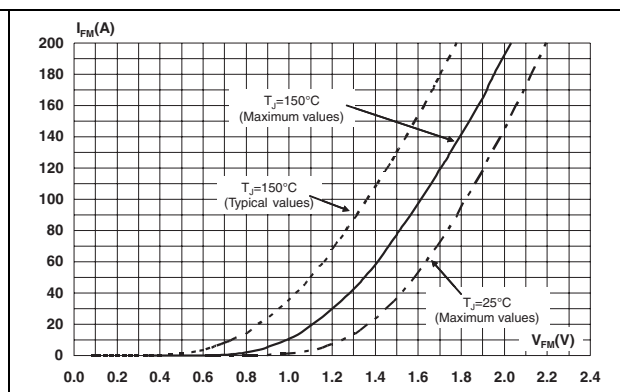


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

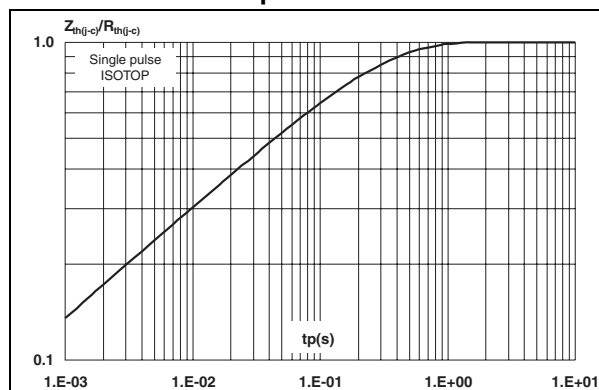


Figure 4. Peak reverse recovery current versus di_F/dt (typical values)

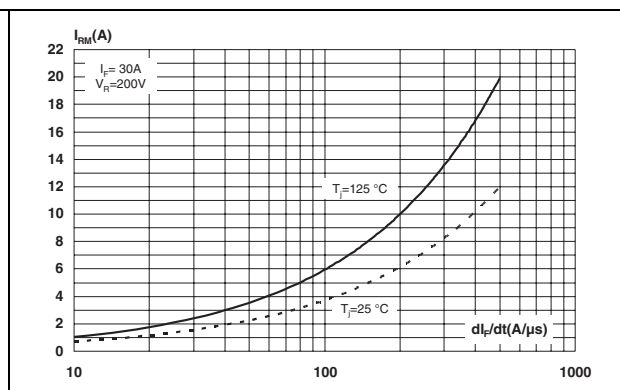


Figure 5. Reverse recovery time versus di_F/dt (typical values)

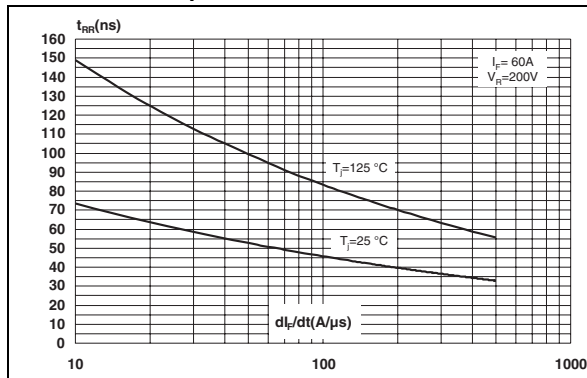


Figure 6. Reverse recovery charges versus di_F/dt (typical values)

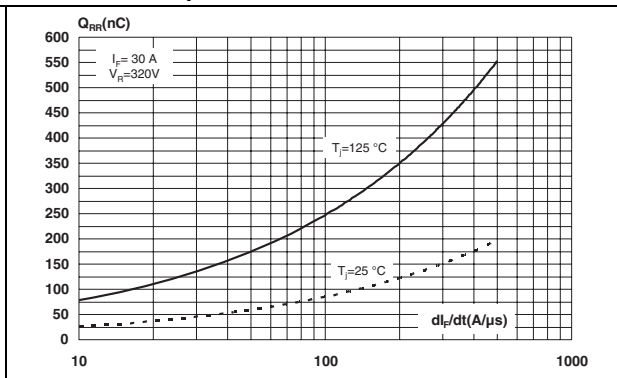


Figure 7. Relative variations of dynamic parameters versus junction temperature

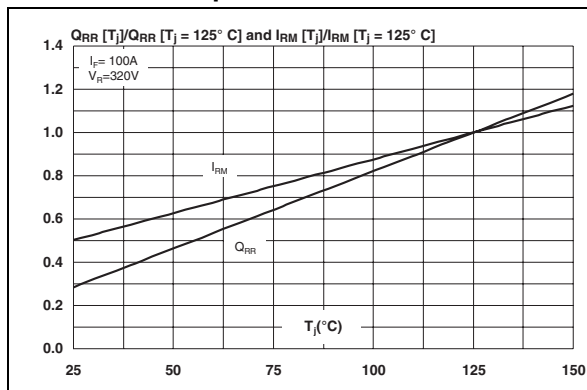


Figure 8. Transient peak forward voltage versus di_F/dt (typical values)

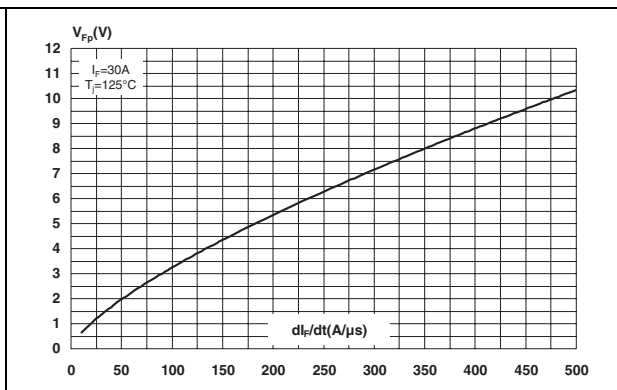


Figure 9. Forward recovery time versus di_F/dt (typical values)

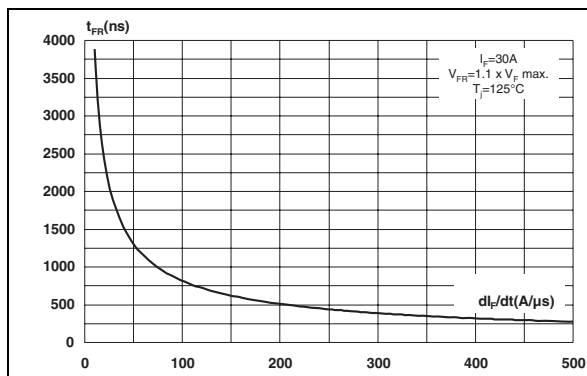
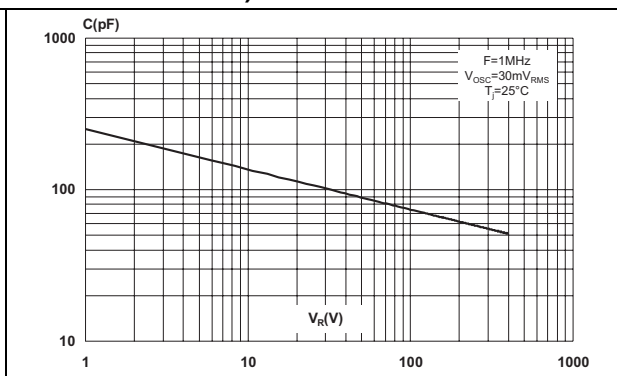


Figure 10. Junction capacitance versus reverse voltage applied (typical values)



2 Package information

Epoxy meets UL94, V0

Cooling method: by conduction (C)

Table 5. ISOTOP dimensions

| Ref. | Dimensions | | | |
|------|-------------|-------|------------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 11.80 | 12.20 | 0.465 | 0.480 |
| A1 | 8.90 | 9.10 | 0.350 | 0.358 |
| B | 7.8 | 8.20 | 0.307 | 0.323 |
| C | 0.75 | 0.85 | 0.030 | 0.033 |
| C2 | 1.95 | 2.05 | 0.077 | 0.081 |
| D | 37.80 | 38.20 | 1.488 | 1.504 |
| D1 | 31.50 | 31.70 | 1.240 | 1.248 |
| E | 25.15 | 25.50 | 0.990 | 1.004 |
| E1 | 23.85 | 24.15 | 0.939 | 0.951 |
| E2 | 24.80 typ. | | 0.976 typ. | |
| G | 14.90 | 15.10 | 0.587 | 0.594 |
| G1 | 12.60 | 12.80 | 0.496 | 0.504 |
| G2 | 3.50 | 4.30 | 0.138 | 0.169 |
| F | 4.10 | 4.30 | 0.161 | 0.169 |
| F1 | 4.60 | 5.00 | 0.181 | 0.197 |
| P | 4.00 | 4.30 | 0.157 | 0.69 |
| P1 | 4.00 | 4.40 | 0.157 | 0.173 |
| S | 30.10 | 30.30 | 1.185 | 1.193 |

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

3 Ordering information

| Part Number | Marking | Package | Weight | Base qty | Delivery mode |
|--------------|--------------|---------|--------|----------|---------------|
| STTH61R04TV1 | STTH61R04TV1 | ISOTOP | 27 g | 10 | Tube |
| STTH61R04TV2 | STTH61R04TV2 | ISOTOP | 27 g | 10 | Tube |

4 Revision history

| Date | Revision | Description of Changes |
|-------------|----------|------------------------|
| 31-Mar-2007 | 1 | First issue |

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